## NSN 5961-01-123-5396

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-123-5396 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.195 inches **End Application:** Integ comm 76301 **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 gate to source voltage and 30.0 drain to source voltage and 30.0 drain to gate voltage **Current Rating Per Characteristic:** 50.00 milliamperes gate current **Power Rating Per Characteristic:** 0.5 watts total power dissipation **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/476 government specification Shelf Life: N/a

No

**Unit Of Measure:** 

**Demilitarization:** 

## **NSN 5961-01-123-5396** Transistor - Page 2 of 2



Fiig:

A110a0